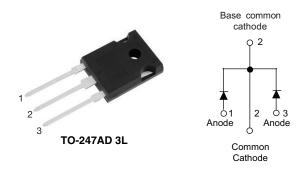
Vishay Semiconductors

# 650 V Power SiC Merged PIN Schottky Diode, 2 x 10 A



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## LINKS TO ADDITIONAL RESOURCES

30	SPICE	
3D Models	Models	Application Notes

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 10 A			
V <sub>R</sub>	650 V			
V <sub>F</sub> at I <sub>F</sub> at 150 °C	1.75 V			
T <sub>J</sub> max.	175 °C			
I <sub>R</sub> at V <sub>R</sub> at 175 °C	10 µA			
Q <sub>C</sub> (V <sub>R</sub> = 400 V)	29 nC			
Package	TO-247AD 3L			
Circuit configuration	Common cathode			

## FEATURES

- Majority carrier diode using Schottky technology on SiC wide band gap material

HALOGEN

- $\bullet$  Positive  $V_{\text{F}}$  temperature coefficient, for easy paralleling
- Virtually no recovery tail and no switching losses
- Temperature invariant switching behavior
- 175 °C maximum operating junction temperature
- MPS structure for high ruggedness to forward current surge events
- Meets JESD 201 class 1A whisker test
- Solder Bath temperature 275 °C maximum, 10 s per JESD 22-B106
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

Wide band gap SiC based 650 V Schottky diode, designed for high performance and ruggedness.

Optimum choice for high speed hard switching and efficient operation over a wide temperature range, it is also recommended for all applications suffering from Silicon ultrafast recovery behavior.

Typical applications include AC/DC PFC and DC/DC ultra high frequency output rectification in FBPS and LLC converters.

### **MECHANICAL DATA**

#### Case: TO-247AD 3L

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

Mounting torque: 10 in-lbs maximum

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise specified)					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V <sub>RRM</sub>		650	V	
Average rectified forward current, per leg	I <sub>F(AV)</sub>	T <sub>C</sub> = 133 °C (DC)	10	Α	
DC blocking voltage	V <sub>DC</sub>		650	V	
Repetitive peak surge current, per leg	I <sub>FRM</sub>	$T_C$ = 25 °C, f = 50 Hz, square wave, DC = 25 $\%$	39		
Non-repetitive peak forward surge current, per leg	I <sub>FSM</sub>	$T_C = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{ half sine wave}$	64	A	
Non-repetitive peak forward surge current, per leg		$T_{C}$ = 110 °C, $t_{p}$ = 10 ms, half sine wave	50		
Power dissipation, per leg	P <sub>tot</sub> <sup>(1)</sup>	$T_{\rm C} = 25^{\circ}{\rm C}$	71	w	
Fower dissipation, per leg		T <sub>C</sub> = 110 °C	31	vv	
12t volue, por log	∫i <sup>2</sup> dt	$T_{\rm C} = 25^{\circ}{\rm C}$	20	A <sup>2</sup> s	
l <sup>2</sup> t value, per leg		T <sub>C</sub> = 110 °C	13		
Operating junction and storage temperatures	T <sub>J</sub> <sup>(2)</sup> , T <sub>Stg</sub>		-55 to +175	°C	

#### Notes

 $^{(1)}\,$  Based on maximum  $R_{th}$ 

<sup>(2)</sup> The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

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<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
		I <sub>F</sub> = 10 A	-	1.50	1.80	
Forward voltage, per leg	VF	I <sub>F</sub> = 10 A, T <sub>J</sub> = 150 °C	-	1.75	1.95	V
		I <sub>F</sub> = 10 A, T <sub>J</sub> = 175 °C	-	1.85	-	
		$V_{R} = V_{R}$ rated	-	-	55	
Reverse leakage current, per leg	I <sub>R</sub>	$V_{R} = V_{R}$ rated, $T_{J} = 150 \text{ °C}$	-	-	125	μA
		$V_R = V_R$ rated, $T_J = 175 \text{ °C}$	-	10	-	
Total consoitance, por log	С	V <sub>R</sub> = 1 V, f = 1 MHz	-	430	-	рF
Total capacitance, per leg	U	V <sub>R</sub> = 400 V, f = 1 MHz	-	45	-	рг
Total capacitive charge, per leg	Q <sub>C</sub>	V <sub>R</sub> = 400 V, f = 1 MHz	-	29	-	nC

<b>THERMAL - MECHANICAL SPECIFICATIONS</b> ( $T_A = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction-to-case	per leg	Bth IC		-	1.5	2.1	°C/W
mermai resistance, junction-to-case	per device			-	0.9	1.3	°C/W
Marking device					C20C	P07L	

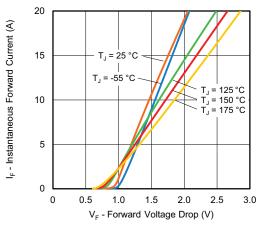


Fig. 1 - Typical Forward Voltage Drop Characteristics, Per leg

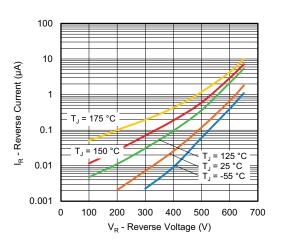


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per leg

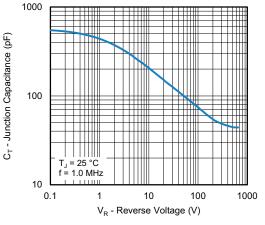


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per leg

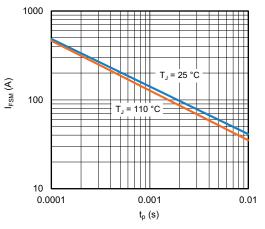


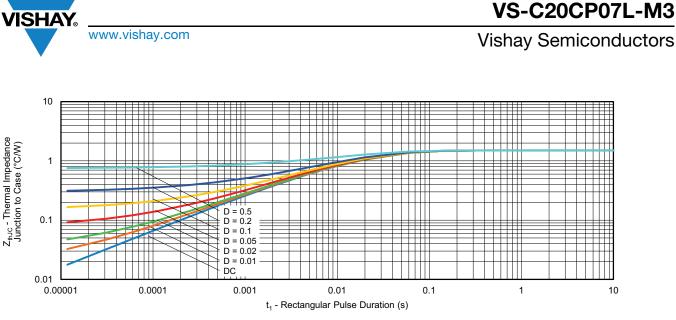
Fig. 4 - Non-Repetitive Peak Forward Surge Current vs. Pulse Duration, Per Leg (Square Wave)

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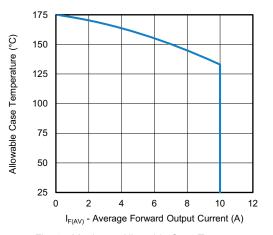


Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current, per leg

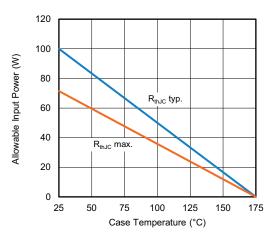


Fig. 7 - Forward Power Loss Characteristics, per leg

11 10 9 8 Capacitive Energy (µJ) 7 6 5 4 3 T<sub>J</sub> = 25 °C f = 1.0 MHz 2 J\_ C V dV  $E_J =$ 1 0 100 200 300 400 600 700 0 500 Reverse Voltage (V)

Fig. 8 - Typical Capacitive Energy vs. Reverse Voltage, per leg

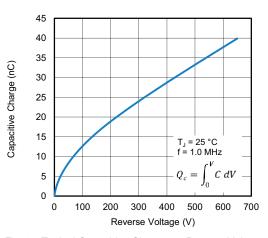


Fig. 9 - Typical Capacitive Charge vs. Reverse Voltage, per leg

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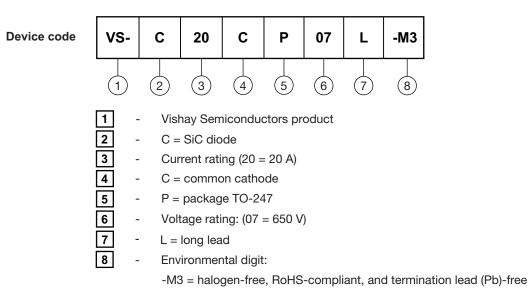
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## **ORDERING INFORMATION TABLE**



ORDERING INFORMATION					
PREFERRED P/N	BASE QUANTITY	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-C20CP07L-M3	25/tube	500	Antistatic plastic tubes		

LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?95626			
Part marking information	www.vishay.com/doc?95007		
SPICE model	www.vishay.com/doc?96887		



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